

MJE5740
MJE5741*
MJE5742*

***Motorola Preferred Device**

- POWER DARLINGTON
TRANSISTORS
8 AMPERES
300, 350, 400 VOLTS
80 WATTS**

THERMAL CHARACTERISTICS

Characteristic	Symbol	Max	Unit
Thermal Resistance, Junction to Case	R _{θJC}	1.56	°C/W
Thermal Resistance, Junction to Ambient	R _{θJA}	62.5	°C/W
Maximum Lead Temperature for Soldering Purposes: 1/8" from Case for 5 Seconds	T _L	275	°C

Characteristic	Symbol	Min	Typ	Max	Unit
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Collector–Emitter Sustaining Voltage ($I_C = 50\text{ mA}$, $I_B = 0$)	MJE5740 MJE5741 MJE5742	$V_{CEO(sus)}$	300 350 400	— — —	— — —	V_{dc}
Collector Cutoff Current ($V_{CEV} = \text{Rated Value}$, $V_{BE(off)} = 1.5\text{ Vdc}$) ($V_{CEV} = \text{Rated Value}$, $V_{BE(off)} = 1.5\text{ Vdc}$, $T_C = 100^\circ\text{C}$)		I_{CEV}	— —	— —	1 5	$mAdc$
Emitter Cutoff Current ($V_{EB} = 8\text{ Vdc}$, $I_C = 0$)		I_{EBO}	—	—	75	$mAdc$

Second Breakdown Collector Current with Base Forward Biased	$I_{S/b}$	See Figure 6
Clamped Inductive SOA with Base Reverse Biased	RBSOA	See Figure 7

(continued)

REV 1

ELECTRICAL CHARACTERISTICS — continued ($T_C = 25^\circ\text{C}$ unless otherwise noted)

Characteristic	Symbol	Min	Typ	Max	Unit
ON CHARACTERISTICS (1)					
DC Current Gain ($I_C = 0.5 \text{ Adc}$, $V_{CE} = 5 \text{ Vdc}$) ($I_C = 4 \text{ Adc}$, $V_{CE} = 5 \text{ Vdc}$)	h_{FE}	50 200	100 400	— —	—
Collector–Emitter Saturation Voltage ($I_C = 4 \text{ Adc}$, $I_B = 0.2 \text{ Adc}$) ($I_C = 8 \text{ Adc}$, $I_B = 0.4 \text{ Adc}$) ($I_C = 4 \text{ Adc}$, $I_B = 0.2 \text{ Adc}$, $T_C = 100^\circ\text{C}$)	$V_{CE(sat)}$	— — —	— — —	2 3 2.2	Vdc
Base–Emitter Saturation Voltage ($I_C = 4 \text{ Adc}$, $I_B = 0.2 \text{ Adc}$) ($I_C = 8 \text{ Adc}$, $I_B = 0.4 \text{ Adc}$) ($I_C = 4 \text{ Adc}$, $I_B = 0.2 \text{ Adc}$, $T_C = 100^\circ\text{C}$)	$V_{BE(sat)}$	— — —	— — —	2.5 3.5 2.4	Vdc
Diode Forward Voltage (2) ($I_F = 5 \text{ Adc}$)	V_f	—	—	2.5	Vdc

SWITCHING CHARACTERISTICS

Typical Resistive Load (Table 1)						
Delay Time	(V _{CC} = 250 Vdc, I _{C(pk)} = 6 A I _{B1} = I _{B2} = 0.25 A, t _p = 25 μs, Duty Cycle ≤ 1%)	t _d	—	0.04	—	μs
Rise Time		t _r	—	0.5	—	μs
Storage Time		t _s	—	8	—	μs
Fall Time		t _f	—	2	—	μs
Inductive Load, Clamped (Table 1)						
Voltage Storage Time	(I _{C(pk)} = 6 A, V _{CE(pk)} = 250 Vdc I _{B1} = 0.06 A, V _{BE(off)} = 5 Vdc)	t _{sv}	—	4	—	μs
Crossover Time		t _c	—	2	—	μs

(1) Pulse Test: Pulse Width $300 \mu\text{s}$, Duty Cycle = 2%.

(2) The internal Collector–to–Emitter diode can eliminate the need for an external diode to clamp inductive loads. Tests have shown that the Forward Recovery Voltage (V_f) of this diode is comparable to that of typical fast recovery rectifiers.

TYPICAL CHARACTERISTICS

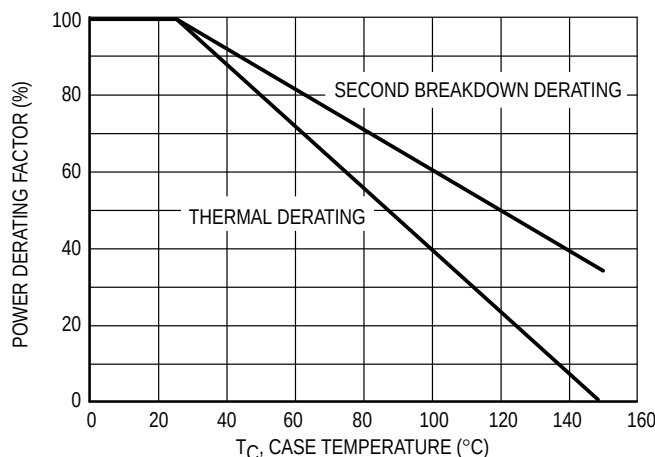


Figure 1. Power Derating

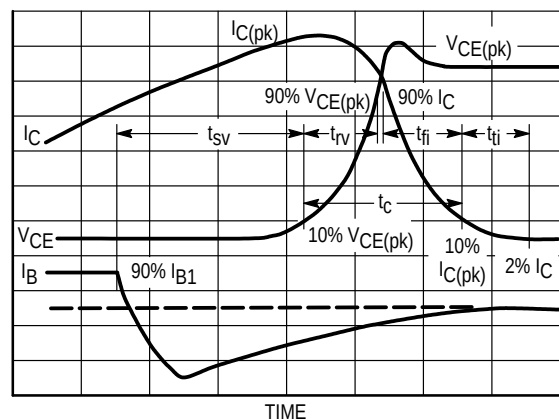


Figure 2. Inductive Switching Measurements

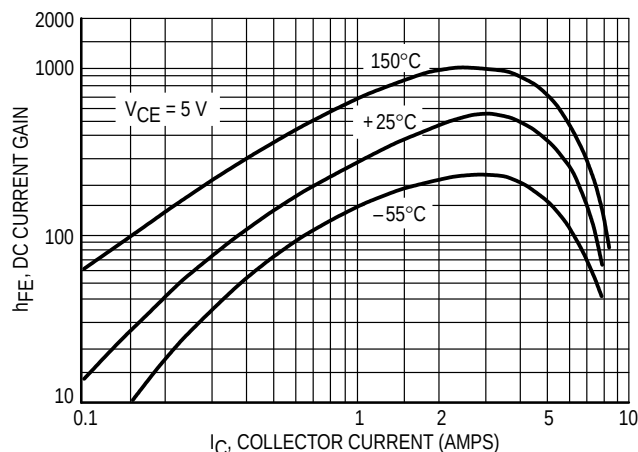


Figure 3. DC Current Gain

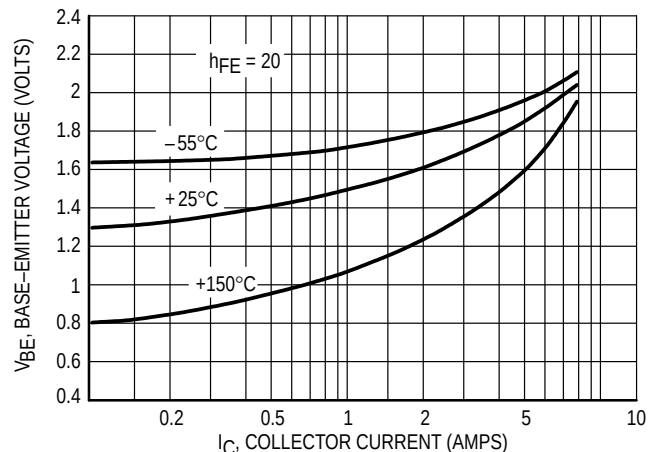


Figure 4. Base–Emitter Voltage

Table 1. Test Conditions for Dynamic Performance

REVERSE BIAS SAFE OPERATING AREA AND INDUCTIVE SWITCHING			RESISTIVE SWITCHING
TEST CIRCUITS	DUTY CYCLE $\leq 10\%$ $t_r, t_f \leq 10 \text{ ns}$ NOTE: PW and V_{CC} Adjusted for Desired I_C R_B Adjusted for Desired I_{B1}		*SELECTED FOR $\geq 1 \text{ kV}$
CIRCUIT VALUES	COIL DATA: FERROXCUBE CORE #6656 FULL BOBBIN (~16 TURNS) #16 GAP FOR 200 $\mu\text{H}/20 \text{ A}$ $L_{\text{coil}} = 200 \mu\text{H}$ $V_{CC} = 30 \text{ V}$ $V_{CE(\text{pk})} = 250 \text{ Vdc}$ $I_{C(\text{pk})} = 6 \text{ A}$		$V_{CC} = 250 \text{ V}$ $D1 = 1\text{N}5820 \text{ OR EQUIV.}$
TEST WAVEFORMS	OUTPUT WAVEFORMS t_1 ADJUSTED TO OBTAIN I_C $t_1 \approx \frac{L_{\text{coil}} (I_{C_{pk}})}{V_{CC}}$ TEST EQUIPMENT SCOPE-TEKTRONICS 475 OR EQUIVALENT $t_2 \approx \frac{L_{\text{coil}} (I_{C_{pk}})}{V_{\text{clamp}}}$		$t_r, t_f < 10 \text{ ns}$ DUTY CYCLE = 1% R_B AND R_C ADJUSTED FOR DESIRED I_B AND I_C

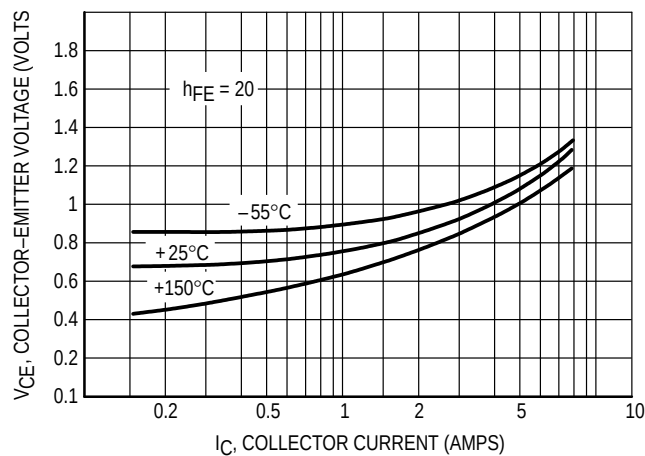


Figure 5. Inductive Switching Measurements

SAFE OPERATING AREA INFORMATION

FORWARD BIAS

There are two limitations on the power handling ability of a transistor: average junction temperature and second breakdown. Safe operating area curves indicate $I_C - V_{CE}$ limits of the transistor that must be observed for reliable operation; i.e., the transistor must not be subjected to greater dissipation than the curves indicate.

The data of Figure 6 is based on $T_C = 25^\circ\text{C}$; $T_J(\text{pk})$ is variable depending on power level. Second breakdown pulse limits are valid for duty cycles to 10% but must be derated when $T_C \geq 25^\circ\text{C}$. Second breakdown limitations do not derate the same as thermal limitations. Allowable current at the voltages shown on Figure 6 may be found at any case temperature by using the appropriate curve on Figure 1.

The Safe Operating Area figures shown in Figures 6 and 7 are specified ratings for these devices under the test conditions shown.

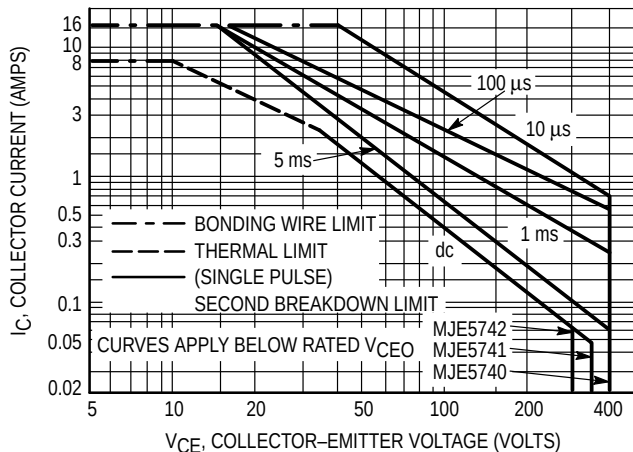


Figure 6. Forward Bias Safe Operating Area

REVERSE BIAS

For inductive loads, high voltage and high current must be sustained simultaneously during turn-off, in most cases, with the base to emitter junction reverse biased. Under these conditions the collector voltage must be held to a safe level at or below a specific value of collector current. This can be accomplished by several means such as active clamping, RC snubbing, load line shaping, etc. The safe level for these devices is specified as Reverse Bias Safe Operating Area and represents the voltage-current condition allowable during reverse biased turnoff. This rating is verified under clamped conditions so that the device is never subjected to an avalanche mode. Figure 7 gives the complete RBSOA characteristics.

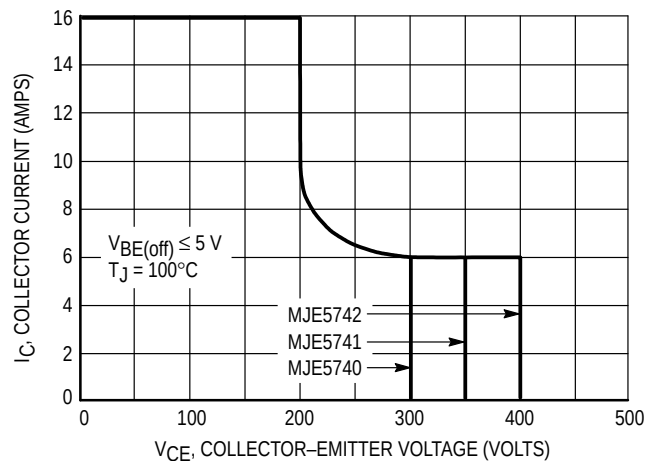


Figure 7. Reverse Bias Safe Operating Area

RESISTIVE SWITCHING PERFORMANCE

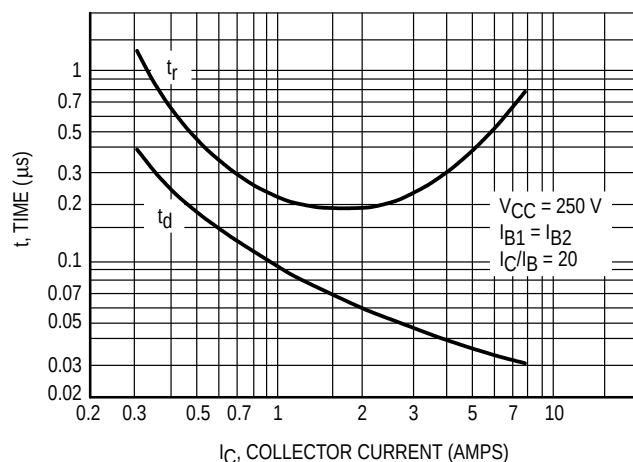


Figure 8. Turn-On Time

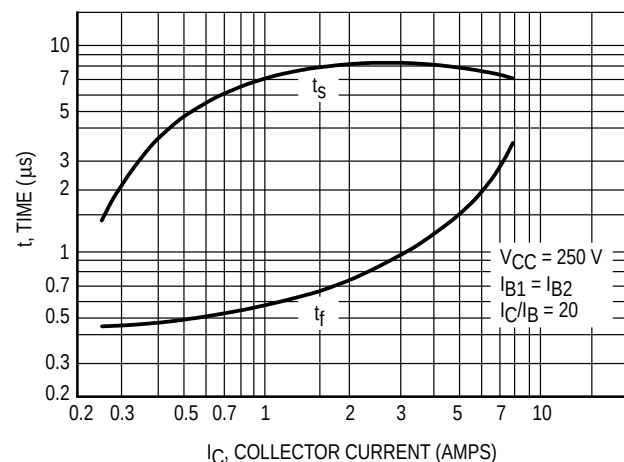
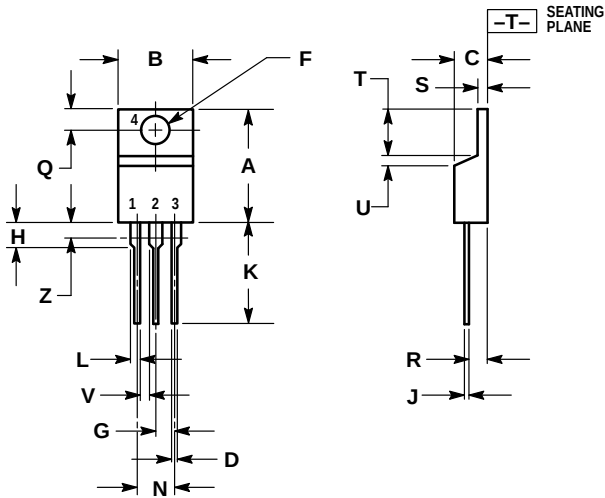


Figure 9. Turn-Off Time

PACKAGE DIMENSIONS



- NOTES:
- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
 - 2. CONTROLLING DIMENSION: INCH.
 - 3. DIMENSION Z DEFINES A ZONE WHERE ALL BODY AND LEAD IRREGULARITIES ARE ALLOWED.

DIM	INCHES		MILLIMETERS	
	MIN	MAX	MIN	MAX
A	0.570	0.620	14.48	15.75
B	0.380	0.405	9.66	10.28
C	0.160	0.190	4.07	4.82
D	0.025	0.035	0.64	0.88
F	0.142	0.147	3.61	3.73
G	0.095	0.105	2.42	2.66
H	0.110	0.155	2.80	3.93
J	0.018	0.025	0.46	0.64
K	0.500	0.562	12.70	14.27
L	0.045	0.060	1.15	1.52
N	0.190	0.210	4.83	5.33
Q	0.100	0.120	2.54	3.04
R	0.080	0.110	2.04	2.79
S	0.045	0.055	1.15	1.39
T	0.235	0.255	5.97	6.47
U	0.000	0.050	0.00	1.27
V	0.045	—	1.15	—
Z	—	0.080	—	2.04

- STYLE 1:
- PIN 1. BASE
 - 2. COLLECTOR
 - 3. EMITTER
 - 4. COLLECTOR

CASE 221A-06
TO-220AB
ISSUE Y

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